

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L3	1	(438/149).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") with direction and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:12			
2	BRS	L4	2	(257/80).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:13			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
3	BRS	L5	6	(257/77).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:13			
4	BRS	L6	2	(257/280).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:13			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
5	BRS	L7	6	(257/E21.054).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:14			
6	BRS	L8	3	(257/E21.06).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:14			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
7	BRS	L9	3	(257/E21.062).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:14			
8	BRS	L10	4	(257/401).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:14			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
9	BRS	L14	0	(438/782).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:16			
10	BRS	L15	4	(438/268).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:16			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
11	BRS	L16	5	(438/149).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:16			
12	BRS	L17	1	(438/507).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:16			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
13	BRS	L18	3	(438/273).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:16			
14	BRS	L19	2	(438/285).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:17			

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
15	BRS	L20	11	((silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:17			



	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors	Ref #
75	BRS	6	silicon with (angle or inclin\$5) with ("100" or "001" or "010") same carrier with ("100" or "001" or "010") with direction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 00:46				S84
76	BRS	7	silicon with (angle or inclin\$5) with ("100" or "001" or "010") and carrier with ("100" or "001" or "010") with direction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 00:46				S85
77	BRS	7	silicon with (angle or inclin\$5) with ("100" or "001" or "010") and carrier with ("100" or "001" or "010") with direction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 00:48				S86
78	BRS	38	silicon with (angle or inclin\$5) with ("100" or "001" or "010") and carrier with ("100" or "001" or "010")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 00:54				S87

	Type	Hits	Search Text	DBs	Time Stamp	Com men ts	Er ro r De fi ni tion	Er ro rs	Ref #
79	BRS	68	silicon with (angle or inclin\$5) with ("100" or "001" or "010") and (carrier or conduction or mobility) with ("100" or "001" or "010")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 00:55				S88
80	BRS	16	silicon with (angle or inclin\$5) with ("100" or "001" or "010") and (carrier or conduction or mobility) with ("100" or "001" or "010") with direction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 00:55				S89
81	BRS	0	(438/782).cccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and step with (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 01:02				S90

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors	Ref #
82	BRS	0	(438/782).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and step and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 01:02				S91
83	BRS	0	(438/782).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 01:02				S92

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors	Ref #
84	BRS	162	("438"/\$).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:13				S93
85	BRS	20	("438"/\$).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") with direction and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 23:12				S94

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors	Ref #
86	BRS	55	("257"/\$).ccls. and (silicon or substrate) with (angle or inclin\$5 or slant\$4) with ("100" or "010" or "001") and (carrier or electron or hole or mobility or conduct\$4) with ("100" or "010" or "001") with direction and (anneal\$4 or heat\$4 or thermal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 01:10				S95
87	IS&R2		("2004152965").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/09/02 01:10				S96
88	BRS	1	2004-444902.NRAN.	DERWENT	2006/09/02 01:11				S97